BTA212B series B

GENERAL DESCRIPTION

Glass passivated high commutation triacs in a plastic envelope suitable for surface mounting intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. These devices will commutate the full rated rms current at the maximum rated junction temperature, without the aid of a snubber.

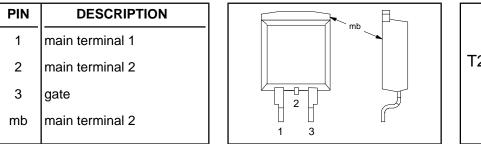
PINNING - SOT404

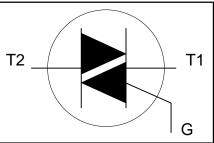
QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MAX. | MAX. | MAX. | UNIT |
|---------------------|---|------|------|------|------|
| | BTA212B- | 500B | 600B | 800B | |
| V _{DRM} | Repetitive peak off-state voltages | 500 | 600 | 800 | V |
| I _{T(RMS)} | RMŠ on-state current | 12 | 12 | 12 | А |
| I _{TSM} | Non-repetitive peak on-state current | 95 | 95 | 95 | A |

PIN CONFIGURATION

SYMBOL





LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | | | UNIT |
|--|---|---|-------------|---------------------------------|---------------------------------|--------------------------|---------|
| V _{DRM} | Repetitive peak off-state voltages | | - | -500 500 ¹ | -600 600 ¹ | -800 800 | v |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 99 °C | - | 12 | | | A |
| I _{TSM} | Non-repetitive peak on-state current | full sine wave; $T_j = 25 \degree C$ prior to surge $t = 20 \ ms$ $t = 16.7 \ ms$ | - | 95 105 | | A | |
| l²t dl _⊤ /dt | I ² t for fusing Repetitive rate of rise of on-state current after triggering | t = 10.7 ms t = 10 ms $I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$ | - | 45 100 | | Α ² s Α/μs | |
| $\begin{array}{l} I_{GM} \\ V_{GM} \\ P_{GM} \\ P_{G(AV)} \end{array}$ | Peak gate current Peak gate voltage Peak gate power Average gate power | over any 20 ms period | - - - | 2 5 5 0.5 | | A V W W | |
| T _{stg} T _j | Storage temperature Operating junction temperature | penou | -40 - | | 150 125 | | ົ ບໍ |

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 $A/\mu s$.

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THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|--|---|------|--------------|-----------------|-------------------|
| R _{th j-mb} R _{th j-a} | Thermal resistance junction to mounting base Thermal resistance junction to ambient | full cycle half cycle in free air | - | - - 60 | 1.5 2.0 - | K/W K/W K/W |

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
|---|-----------------------------------|--|--------|--------|------|------|------|
| I _{GT} | Gate trigger current ² | $V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$ | | | | | |
| 01 | | | T2+ G+ | 2 | 18 | 50 | mA |
| | | | T2+ G- | 2 2 | 21 | 50 | mA |
| | | | T2- G- | 2 | 34 | 50 | mA |
| IL. | Latching current | $V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$ | | | | | |
| | _ | | T2+ G+ | - | 31 | 60 | mA |
| | | | T2+ G- | - | 34 | 90 | mA |
| | | | T2- G- | - | 30 | 60 | mA |
| I _H | Holding current | $V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$ | | - | 31 | 60 | mA |
| I _H V _T V _{GT} | On-state voltage | $I_{T} = 17 \text{ A}$ | | - | 1.3 | 1.6 | V |
| V _{GT} | Gate trigger voltage | $V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$ | | - | 0.7 | 1.5 | V |
| | - | $V_{\rm D} = 400$ V; $I_{\rm T} = 0.1$ A; $T_{\rm i} = 125$ | °C | 0.25 | 0.4 | - | V |
| I _D | Off-state leakage current | $V_{\rm D} = V_{\rm DRM(max)}; T_{\rm j} = 125 ^{\circ}{\rm C}$ | | - | 0.1 | 0.5 | mA |

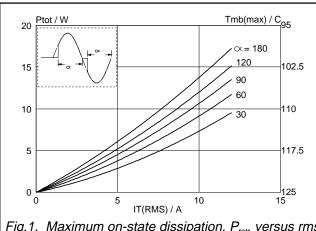
DYNAMIC CHARACTERISTICS

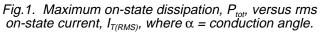
 $T_j = 25$ °C unless otherwise stated

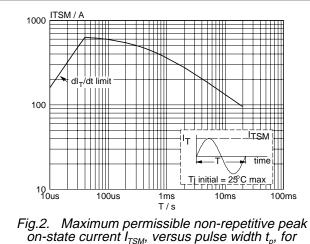
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-----------------------|--|--|------|------|------|------|
| dV _D /dt | Critical rate of rise of off-state voltage | $V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ | 1000 | 4000 | - | V/µs |
| dl _{com} /dt | Critical rate of change of | exponential waveform; gate open circuit $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ I}_{T(RMS)} = 12 \text{ A};$ | - | 24 | - | A/ms |
| t _{gt} | commutating current Gate controlled turn-on time | without snubbér; gate open circuit $I_{TM} = 12 \text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1 \text{ A}$; $dI_G/dt = 5 \text{ A}/\mu \text{s}$ | - | 2 | - | μs |

² Device does not trigger in the T2-, G+ quadrant.

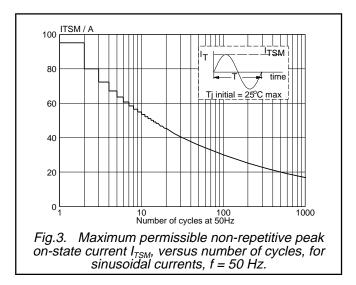
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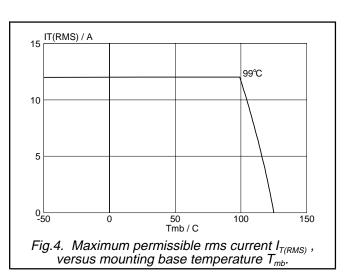






on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \le 20$ ms.





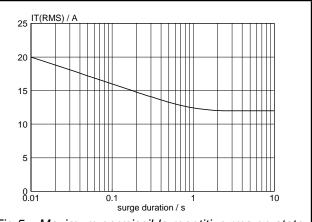
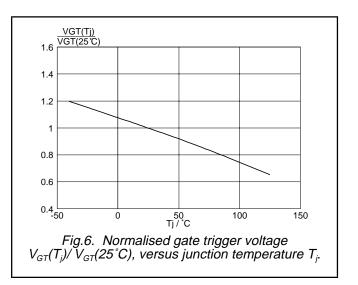
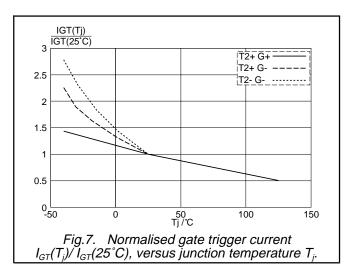
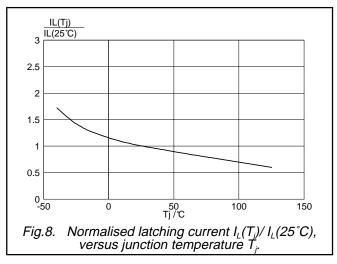


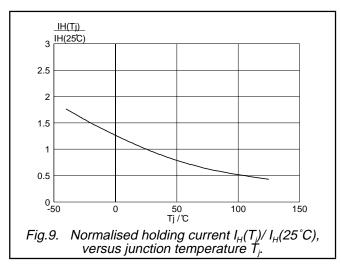
Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 99^{\circ}C$.

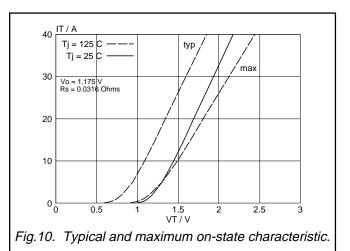


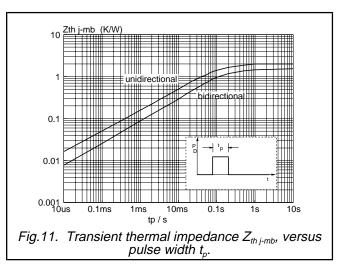
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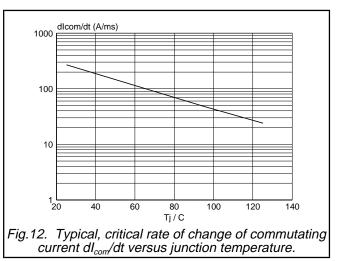






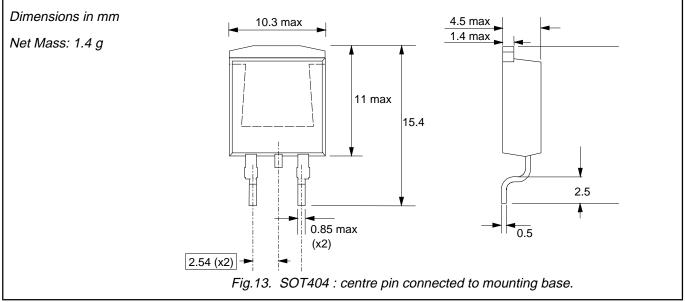






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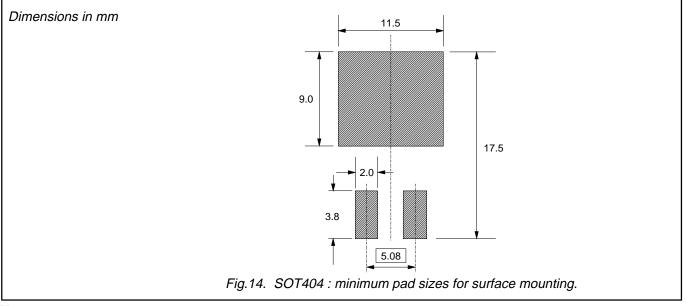
MECHANICAL DATA



Notes

1. Epoxy meets UL94 V0 at 1/8".

MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

BTA212B series B

DEFINITIONS

| Data sheet status | | | | |
|--|--|--|--|--|
| Objective specification | This data sheet contains target or goal specifications for product development. | | | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later | | | |
| Product specification | This data sheet contains final product specifications. | | | |
| Limiting values | | | | |
| Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above on or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | | | | |
| Application information | l | | | |
| Where application inform | ation is given, it is advisory and does not form part of the specification. | | | |
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